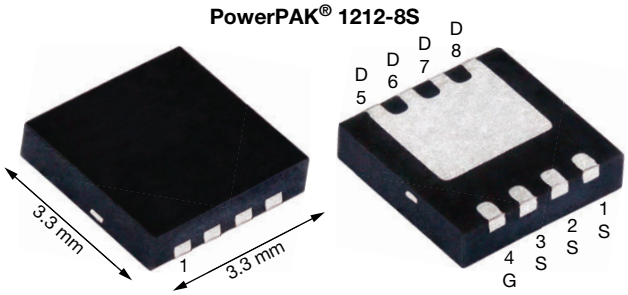
N-Channel 30 V (D-S) MOSFET

PowerPAK® 1212-8S



Top View Bottom View

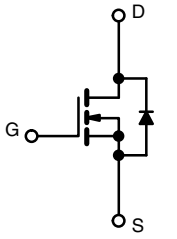
FEATURES

- TrenchFET® Gen IV power MOSFET
- Very low $R_{DS(on)}$ in a compact and thermally enhanced package
- Optimized Q_g, Q_{gd}, and Q_{gd}/Q_{gs} ratio reduces switching related power loss
- 100 % R_g and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

RoHS COMPLIANT
HALOGEN FREE

APPLICATIONS

- Synchronous rectification
- Synchronous buck converter
- High power density DC/DC
- OR-ing
- Load switching



N-Channel MOSFET

PRODUCT SUMMARY	
V_{DS} (V)	30
$R_{DS(on)}$ max. (Ω) at V_{GS} = 10 V	0.00138
$R_{DS(on)}$ max. (Ω) at V_{GS} = 4.5 V	0.00203
Q_g typ. (nC)	24.6
I_D (A)	172.6 [a]
Configuration	Single

ORDERING INFORMATION	
Package	PowerPAK 1212-8S
Lead (Pb)-free and halogen-free	SiSS06DN-T1-GE3

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNIT
Drain-source voltage		V_{DS}	30	V
Gate-source voltage		V_{GS}	+20 / -16	
Continuous drain current (T_J = 150 °C)	T_C = 25 °C	I_D	172.6	A
	T_C = 70 °C		138.1	
	T_A = 25 °C		47.6 [b, c]	
	T_A = 70 °C		38.1 [b, c]	
Pulsed drain current (t = 100 µs)		I_{DM}	300	
Continuous source-drain diode current	T_C = 25 °C	I_S	59.7	
	T_A = 25 °C		4.5 [b, c]	
Single pulse avalanche current	L = 0.1 mH	I_{AS}	30	
Single pulse avalanche energy		E_{AS}	45	mJ
Maximum power dissipation	T_C = 25 °C	P_D	65.7	W
	T_C = 70 °C		42	
	T_A = 25 °C		5 [b, c]	
	T_A = 70 °C		3.2 [b, c]	
Operating junction and storage temperature range		T_J, T_{stg}	-55 to +150	°C
Soldering recommendations (peak temperature) [c]			260	

THERMAL RESISTANCE RATINGS

PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction-to-ambient [b]	t ≤ 10 s	R_{thJA}	20	25	°C/W
Maximum junction-to-case (drain)	Steady state	R_{thJC}	1.5	1.9	

Notes
a. T_C = 25 °C
b. Surface mounted on 1" x 1" FR4 board
c. t = 10 s
d. See solder profile (www.vishay.com/doc?73257). The PowerPAK 1212-8S is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components
f. Maximum under steady state conditions is 63 °C/W

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SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)						
PARAMETER	**SYMBOL**	**TEST CONDITIONS**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static						
Drain-source breakdown voltage	V_{DS}	V_{GS} = 0 V, I_D = 250 µA	30	-	-	V
V_{DS} temperature coefficient	$\Delta V_{DS}/T_J$	I_D = 10 mA	-	26	-	mV/°C
$V_{GS(th)}$ temperature coefficient	$\Delta V_{GS(th)}/T_J$	I_D = 250 µA	-	-5.1	-	
Gate-source threshold voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA	1	-	2.2	V
Gate-source leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = +20 / -16 V	-	-	100	nA
Zero gate voltage drain current	I_{DSS}	V_{DS} = 30 V, V_{GS} = 0 V	-	-	1	µA
		V_{DS} = 30 V, V_{GS} = 0 V, T_J = 70 °C	-	-	15	
On-state drain current [a]	$I_{D(on)}$	$V_{DS} \geq$ 10 V, V_{GS} = 10 V	30	-	-	A
Drain-source on-state resistance [a]	$R_{DS(on)}$	V_{GS} = 10 V, I_D = 15 A	-	0.00115	0.00138	Ω
		V_{GS} = 4.5 V, I_D = 10 A	-	0.00169	0.00203	
Forward transconductance [a]	g_{fs}	V_{DS} = 15 V, I_D = 15 A	-	95	-	S
Dynamic [b]						
Input capacitance	C_{iss}	V_{DS} = 15 V, V_{GS} = 0 V, f = 1 MHz	-	3660	-	pF
Output capacitance	C_{oss}		-	1600	-	
Reverse transfer capacitance	C_{rss}		-	120	-	
Total gate charge	Q_g	V_{DS} = 15 V, V_{GS} = 10 V, I_D =10 A	-	51.1	77	nC
		V_{DS} = 15 V, V_{GS} = 4.5 V, I_D = 10 A	-	24.6	36	
Gate-source charge	Q_{gs}		-	9.8	-	
Gate-drain charge	Q_{gd}		-	4.9	-	
Gate resistance	R_g	f = 1 MHz	0.2	0.7	1.3	Ω
Turn-on delay time	$t_{d(on)}$	V_{DD} = 15 V, R_L = 1.5 Ω, $I_D \cong$ 10 A, V_{GEN} = 10 V, R_g = 1 Ω	-	13	26	ns
Rise time	t_r		-	8	16	
Turn-off delay time	$t_{d(off)}$		-	30	60	
Fall time	t_f		-	10	20	
Turn-on delay time	$t_{d(on)}$	V_{DD} = 15 V, R_L = 1.5 Ω, $I_D \cong$ 10 A, V_{GEN} = 4.5 V, R_g = 1 Ω	-	28	56	
Rise time	t_r		-	60	120	
Turn-off delay time	$t_{d(off)}$		-	35	70	
Fall time	t_f		-	15	30	
Drain-Source Body Diode Characteristics						
Continuous source-drain diode current	I_S	T_C = 25 °C	-	-	59.7	A
Pulse diode forward current	I_{SM}		-	-	300	
Body diode voltage	V_{SD}	I_S = 5 A, V_{GS} = 0 V	-	0.72	1.1	V
Body diode reverse recovery time	t_{rr}	I_F = 15 A, di/dt = 100 A/µs, T_J = 25 °C	-	43	86	ns
Body diode reverse recovery charge	Q_{rr}		-	38	76	nC
Reverse recovery fall time	t_a		-	23	-	ns
Reverse recovery rise time	t_b		-	20	-	

Notes

a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %

b. Guaranteed by design, not subject to production testing

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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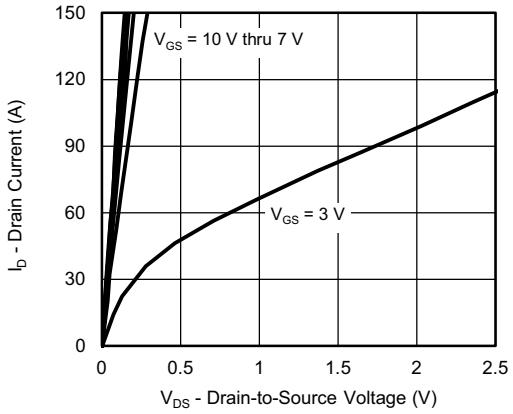
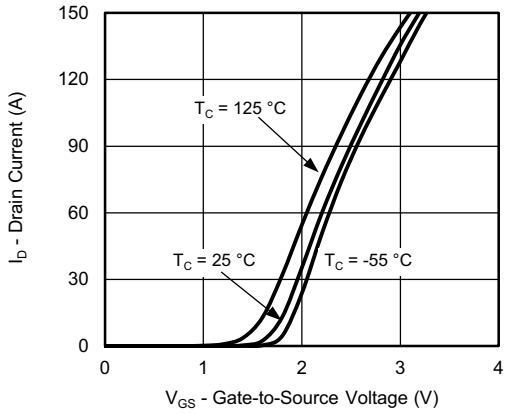
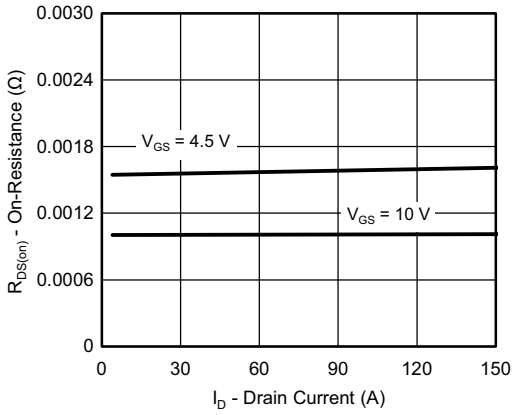


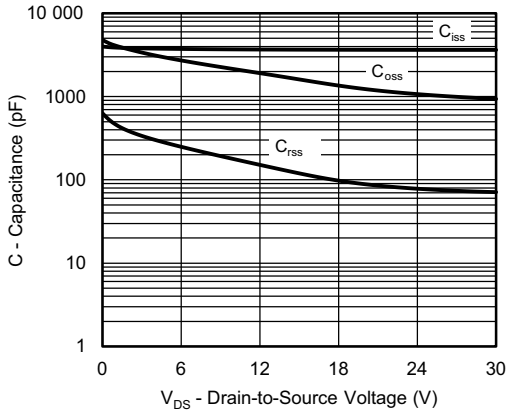
Output Characteristics



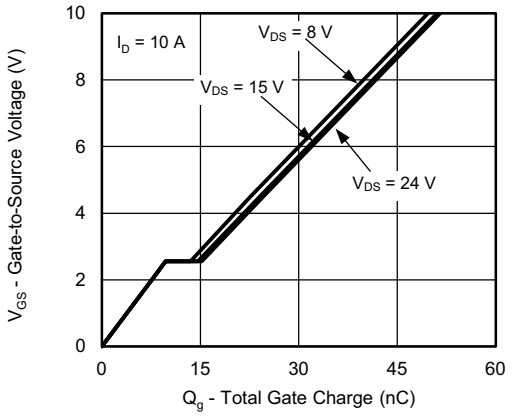
Transfer Characteristics



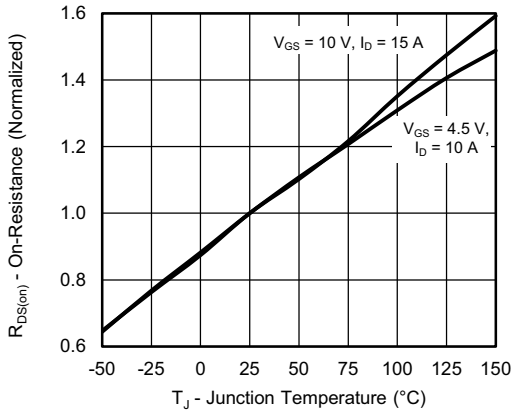
On-Resistance vs. Drain Current and Gate Voltage



Capacitance



Gate Charge



On-Resistance vs. Junction Temperature

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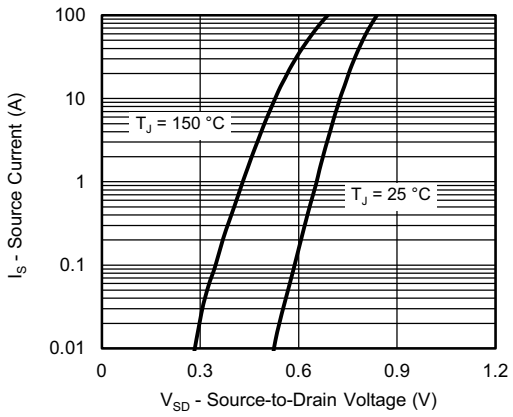
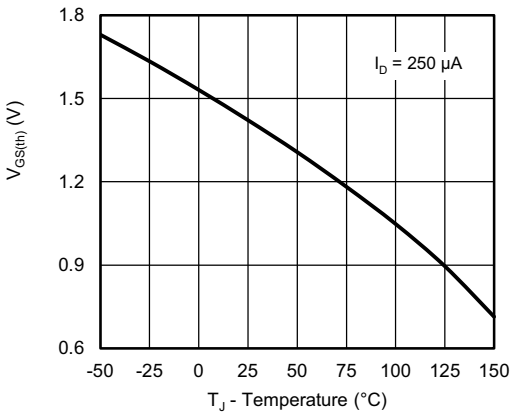
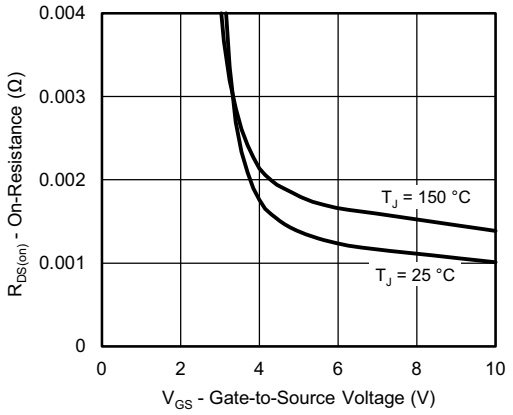


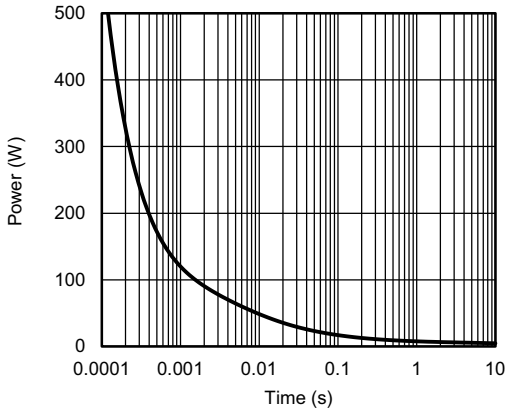
Source-Drain Diode Forward Voltage



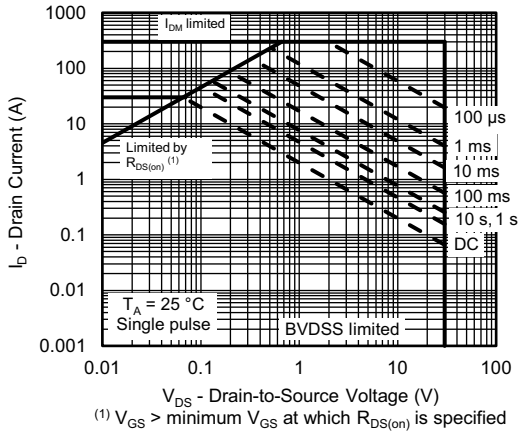
Threshold Voltage



On-Resistance vs. Gate-to-Source Voltage



Single Pulse Power, Junction-to-Ambient



Safe Operating Area, Junction-to-Ambient

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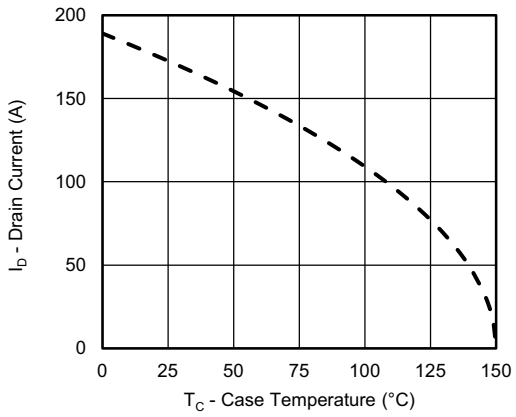
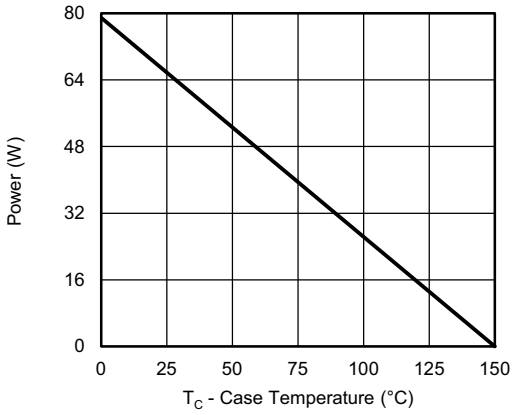
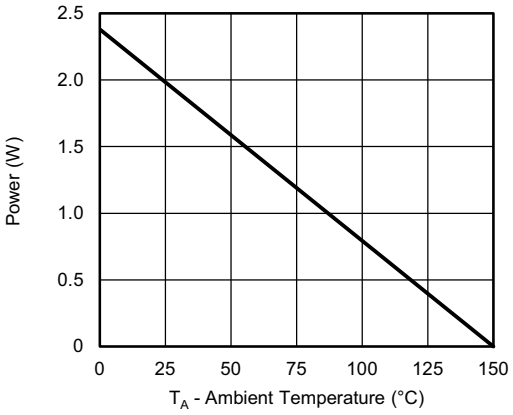


Current Derating [a]



Power, Junction-to-Case (Drain)



Power, Junction-to-Ambient

Note

a. The power dissipation P_D is based on T_J max. = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit

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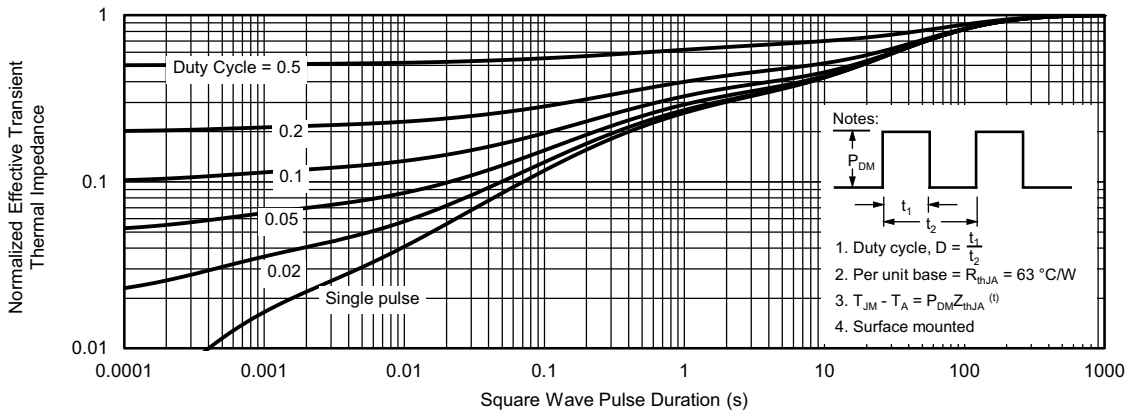
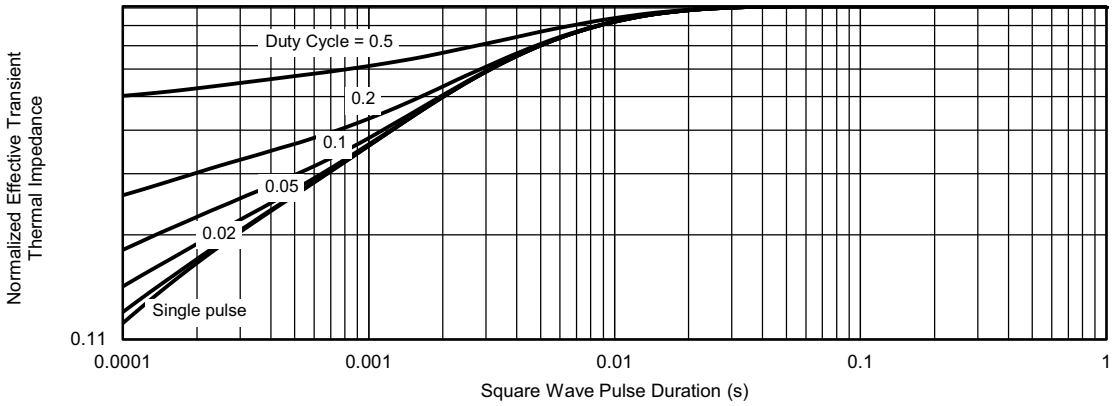


Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case (Drain)

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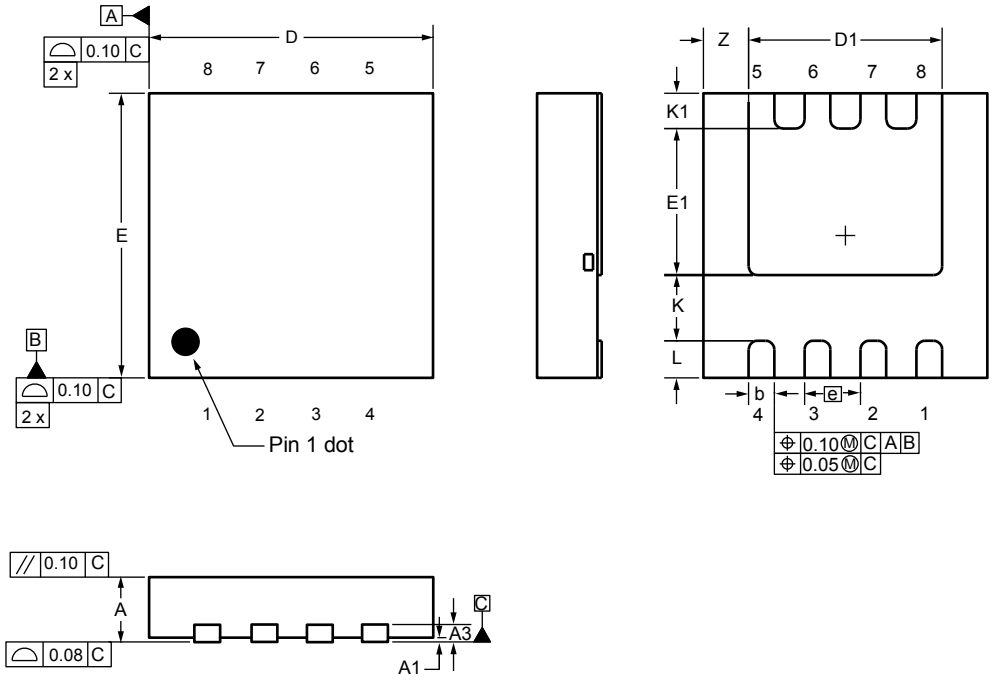
Case Outline for PowerPAK® 1212-8S



DIM.	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.67	0.75	0.83	0.026	0.030	0.033
A1	0.00	-	0.05	0.000	-	0.002
A3	0.20 ref.			0.008 ref		
b	0.25	0.30	0.35	0.010	0.012	0.014
D	3.20	3.30	3.40	0.126	0.130	0.134
D1	2.15	2.25	2.35	0.085	0.089	0.093
E	3.20	3.30	3.40	0.126	0.130	0.134
E1	1.60	1.70	1.80	0.063	0.067	0.071
e	0.65 bsc.			0.026 bsc.		
K	0.76 ref.			0.030 ref.		
K1	0.41 ref.			0.016 ref.		
L	0.33	0.43	0.53	0.013	0.017	0.021
Z	0.525 ref.			0.021 ref.		
ECN: C20-0862-Rev. B, 20-Jul-2020 DWG: 6008						

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